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## Author's Journal Publications

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1. A. Verma, P. K. Sahu, V. Chaudhary, A. K. Singh, V. N. Mishra, and R. Prakash, "Fabrication and Characterization of P3HT/MoS<sub>2</sub> Thin-Film Based Ammonia Sensor Operated at Room Temperature," *IEEE Sensors Journal*, vol. 22, no. 11, pp. 10361-10369, 1 June 1, 2022, doi: 10.1109/JSEN.2022.3170698.
2. A. Verma, V. N. Mishra, and R. Prakash, "A Self-Aligned, Solution-Processed Low-Voltage Operated Organic Thin-Film Transistor for Ammonia Gas Sensing at Room Temperature," *IEEE Sensors Journal*, vol. 23, no. 6, pp. 5561-5568, 15 March 15, 2023, doi: 10.1109/JSEN.2023.3236438.
3. A. Verma, V. N. Mishra, and R. Prakash, "Self-Assembled Au/P3HT, High-k Bilayer Dielectric-Based Solution Processed Low Voltage OTFT for Multiparametric Ammonia Sensor at Room Temperature," *IEEE Transactions on Electron Devices*, vol. 70, no. 1, pp. 281-287, Jan. 2023, doi: 10.1109/TED.2022.3224092.
4. A. Verma, S. Gupta, V. N. Mishra, and R. Prakash, "A Low-Voltage, Self-Oriented Organic Polymer Nanocomposite-Based Flexible TFT for Ammonia Gas Sensing at Room Temperature," *IEEE Transactions on Electron Devices*, vol. 70, no. 5, pp. 2453-2459, May 2023, doi: 10.1109/TED.2023.3255835.
5. A. Verma, P. Kumar, V. K. Singh, V. N. Mishra, and R. Prakash, "Introduction of graphene oxide nanosheets in self-oriented air-stable poly(3-hexylthiophene-2,5-diyl) to enhance the ammonia gas sensing of a p-channel thin film transistor," *Sensors Actuators B Chem.*, vol. 385, p. 133661, Jun. 2023, doi: 10.1016/J.SNB.2023.133661.
6. A. Verma, V. N. Mishra, and R. Prakash, "Air-Stable Highly Sensitive Self-Assembled P3HT/GQD Nanocomposite-Based Organic Thin-Film Transistor for Multiparametric H<sub>2</sub>S Real-Time Detection at Room Temperature," *IEEE Sensors Journal*, vol. 23, no. 1, pp. 127-134, 1 Jan.1, 2023, doi: 10.1109/JSEN.2022.3221997.
7. A. Verma, D. Kumar, V. N. Mishra, and R. Prakash, "A Self-Assembled Polymer Nanocomposite-Based Low-Voltage White Light Phototransistor With UV-Cured Synthesized LaZrOx Dielectric," *IEEE Transactions on Electron Devices*, vol. 70, no. 7, pp. 3575-3581, July 2023, doi: 10.1109/TED.2023.3274500.
8. V. K. Singh, A. Verma, P. Kumar and V. N. Mishra, "Solution-processed, Highly-efficient Organic Field-effect Transistor based Hydrogen Sulfide Gas Sensor at sub-ppm Regime," in *IEEE Sensors Journal*, doi: 10.1109/JSEN.2023.3288932 (Accepted).

## **Author's Conference Publications**

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### **Accepted**

1. **Ankit Verma, Varun Kumar Singh, Prashant Kumar, V. N. Mishra, R. Prakash, “A Self-Oriented polymer/Carbon Dot nanocomposite-based TFT for H<sub>2</sub>S gas sensor using Floating Film Transfer Deposited Sensing Film.”** 2023 *International Conference on Nanoelectronics, Nanophotonics, Nanomaterials, Nanobioscience & Nanotechnology (5NANO) (Accepted)*.
2. **Varun Kumar Singh, Ankit Verma, Prashant Kumar, V. N. Mishra, R. Prakash, “Fully Solution-Processed, Small Molecule Organic Polymer based One-Step Fabrication of Ammonia Gas sensor.”** 2023 *International Conference on Nanoelectronics, Nanophotonics, Nanomaterials, Nanobioscience & Nanotechnology (5NANO) (Accepted)*.
3. **Ankit Verma, V. K. Singh, V. N. Mishra, “Design and Simulation of Low leakage current SRAM cell design with Sleepy Stack Technique,”** 2023 *International Conference on Nanoelectronics, Nanophotonics, Nanomaterials, Nanobioscience & Nanotechnology (5NANO) (Accepted)*.

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